



MCH5908

N-Channel JFET 15V, 10 to 32mA, 35mS, Dual MCPH5

ON Semiconductor®

<http://onsemi.com>

Features

- Composite type with 2 J-FET contained in a MCPH5 package currently in use, improving the mounting efficiency greatly
- The MCH5908 is formed with two chips, being equivalent to the 2SK3557, placed in one package

Specifications

Absolute Maximum Ratings at Ta=25°C

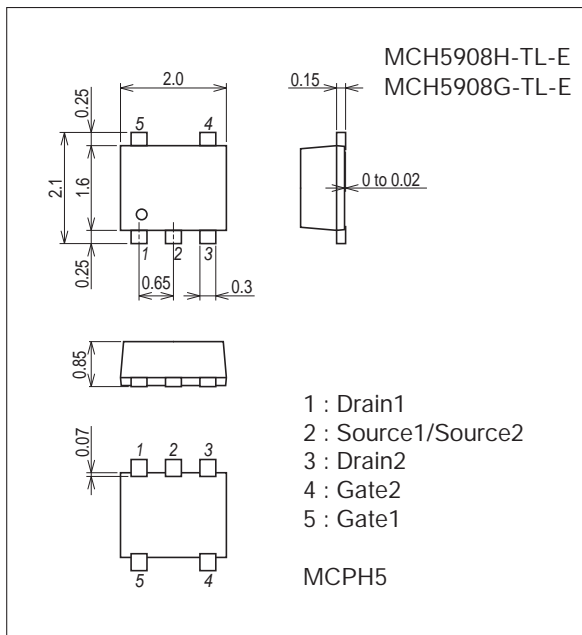
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSX}		15	V
Gate-to-Drain Voltage	V _{GDS}		-15	V
Gate Current	I _G		10	mA
Drain Current	I _D		50	mA
Allowable Power Dissipation	P _D	1 unit	200	mW
Total Power Dissipation	P _T		300	mW
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

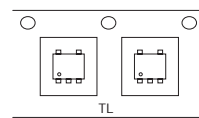
7021A-009



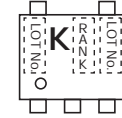
Product & Package Information

- Package : MCPH5
- JEITA, JEDEC : SC-88A, SC-70-5, SOT-353
- Minimum Packing Quantity : 3,000 pcs./reel

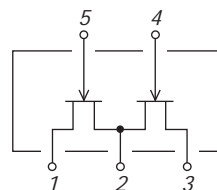
Packing Type : TL



Marking



Electrical Connection



MCH5908

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gate-to-Drain Breakdown Voltage	V(BR)GDS	I _G =-10μA, V _{DS} =0V	-15			V
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =-10V, V _{DS} =0V			-1.0	nA
Cutoff Voltage	V _{GS(off)}	V _{DS} =5V, I _D =100μA	-0.3	-0.7	-1.5	V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =5V, V _{GS} =0V	10.0*		32.0*	mA
Forward Transfer Admittance	y _{fs}	V _{DS} =5V, V _{GS} =0V, f=1kHz	24	35		mS
Input Capacitance	C _{iss}	V _{DS} =5V, V _{GS} =0V, f=1MHz		10.5		pF
Reverse Transfer Capacitance	C _{rss}			3.5		pF
Noise Figure	NF	V _{DS} =5V, R _g =1kΩ, I _D =1mA, f=1kHz		1.0		dB

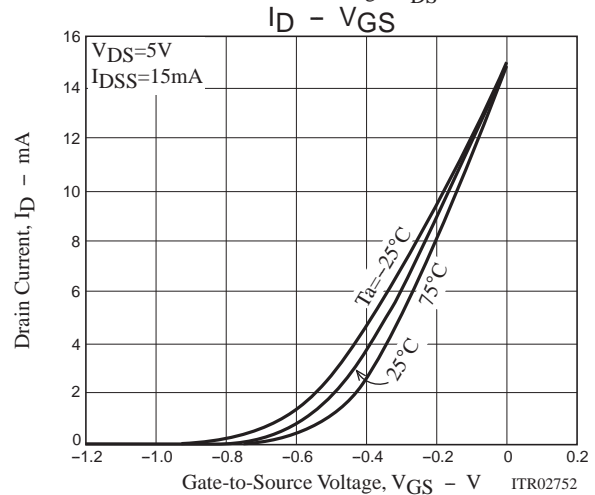
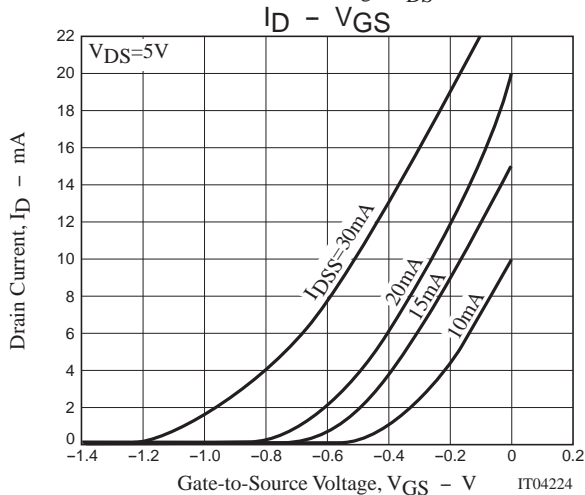
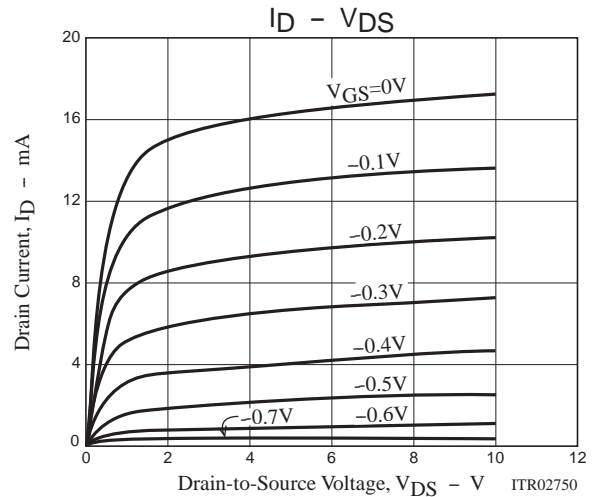
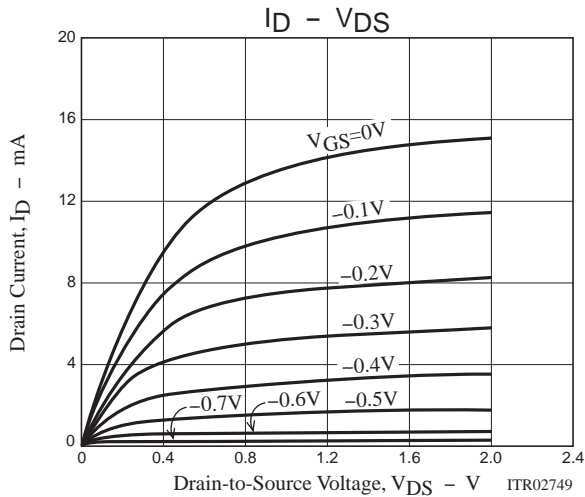
The specifications shown above are for each individual J-FET.

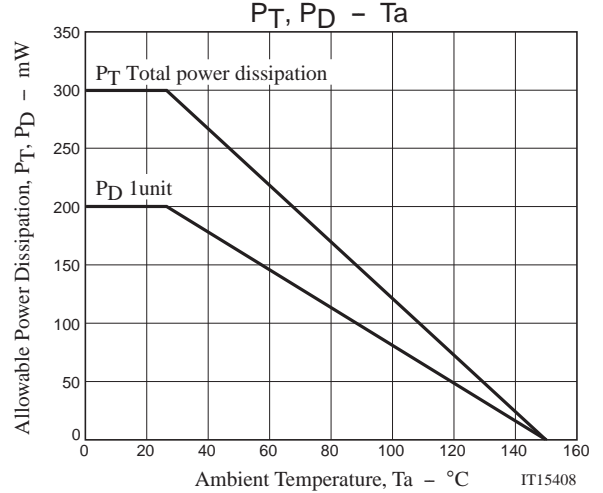
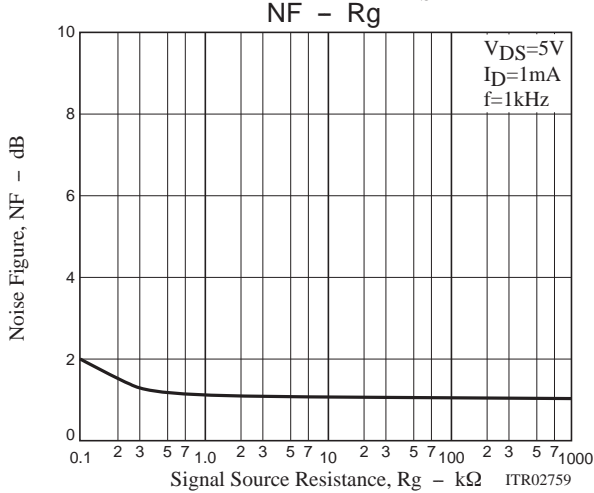
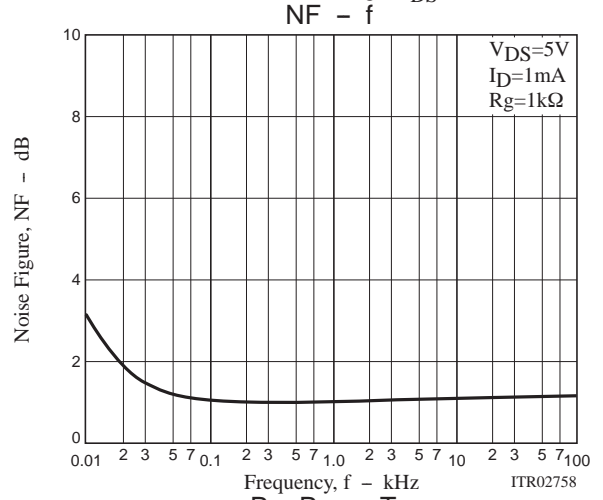
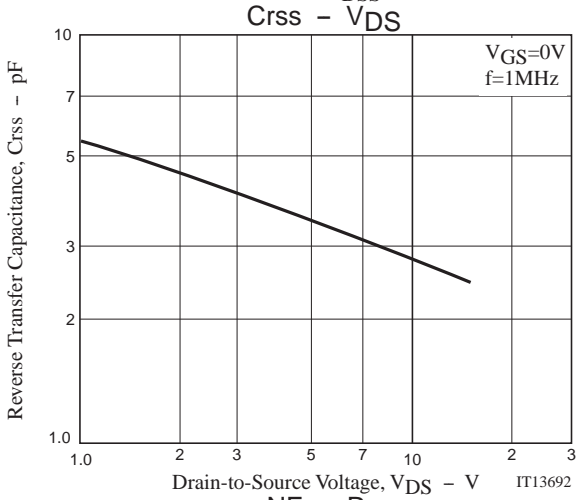
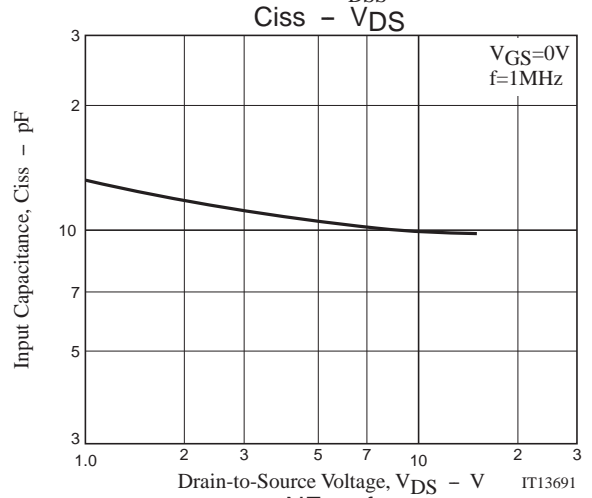
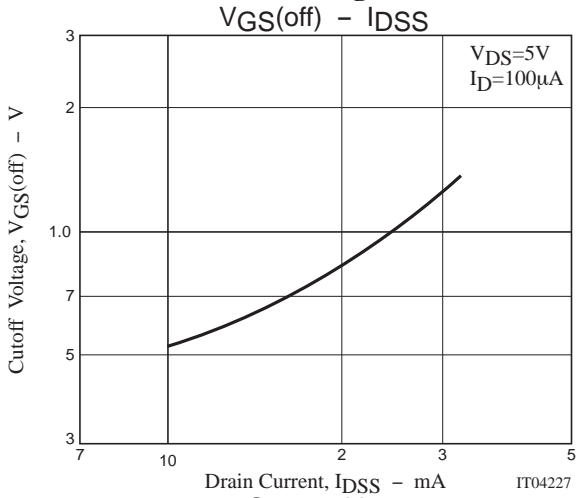
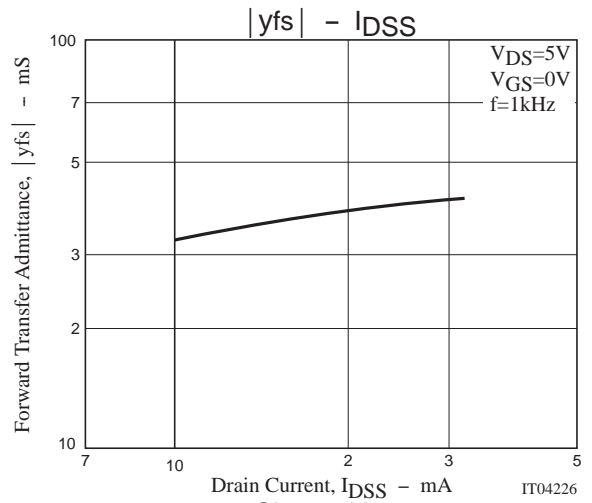
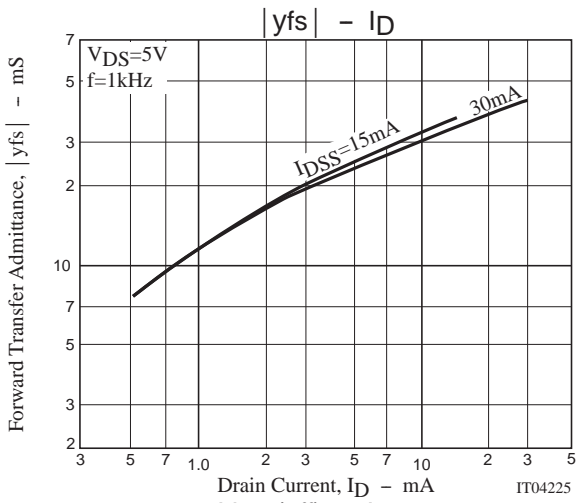
* : The MCH5908 is classified by I_{DSS} as follows (unit : mA).

Rank	G	H
I _{DSS}	10 to 20	16 to 32

Ordering Information

Device	Package	Shipping	memo
MCH5908H-TL-E	MCPH5	3,000pcs./reel	Pb Free
MCH5908G-TL-E	MCPH5	3,000pcs./reel	





Taping Specification

MCH5908H-TL-E, MCH5908G-TL-E

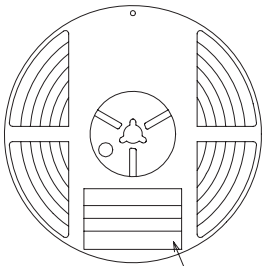
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCPH5	MCP4	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit : mm)

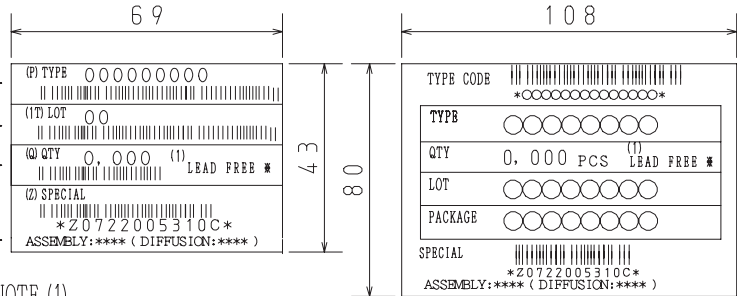
Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Type No.
LOT No.
Quantity
Origin

Reel label



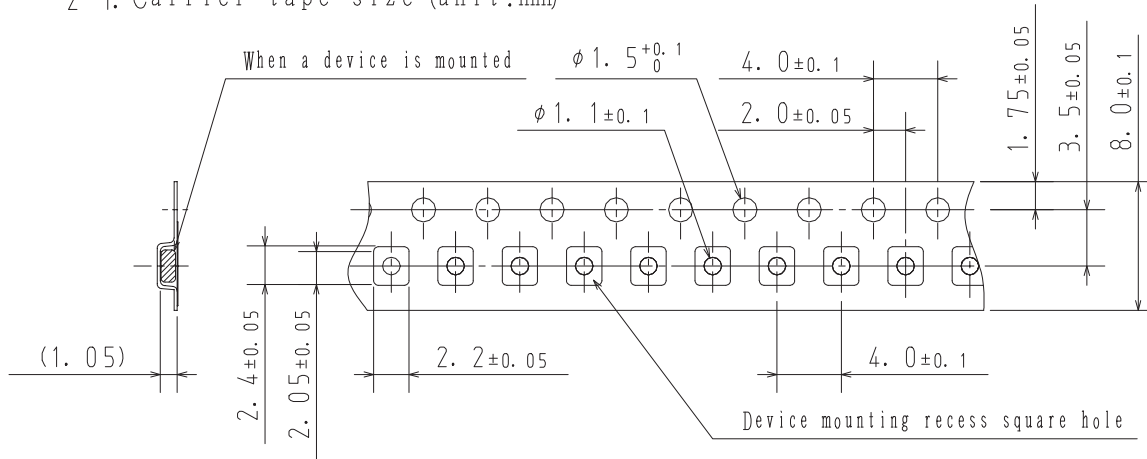
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

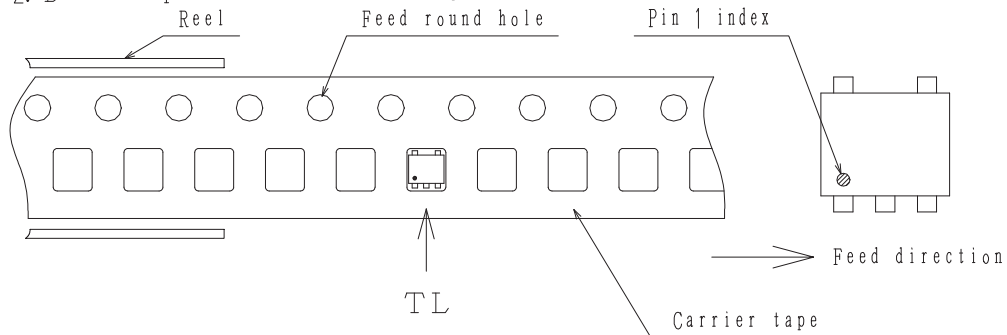
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

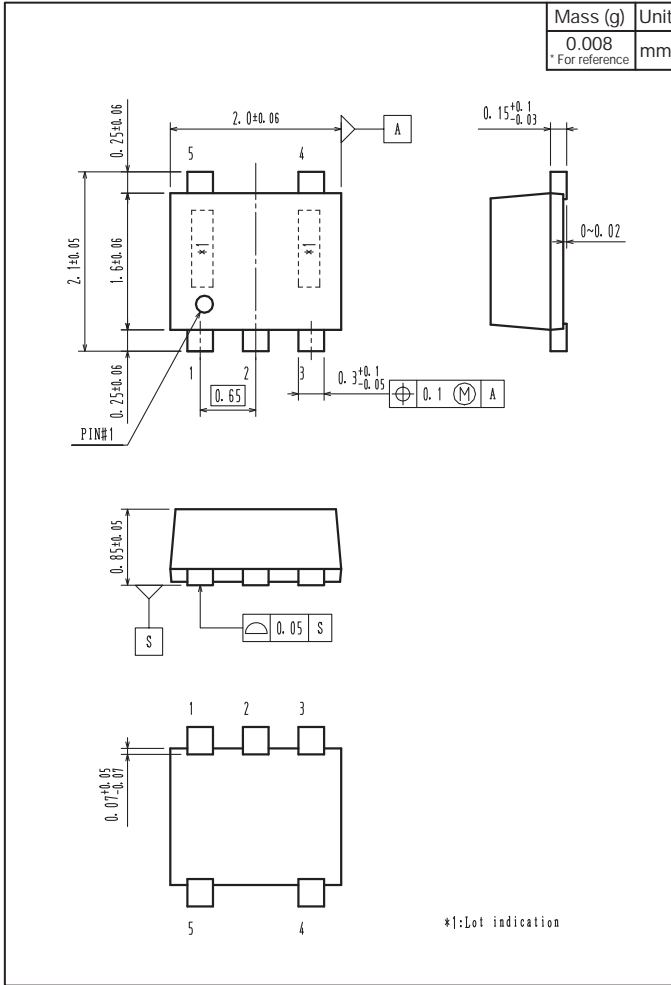


Those with two electrode terminal on the feed hole side.....TL

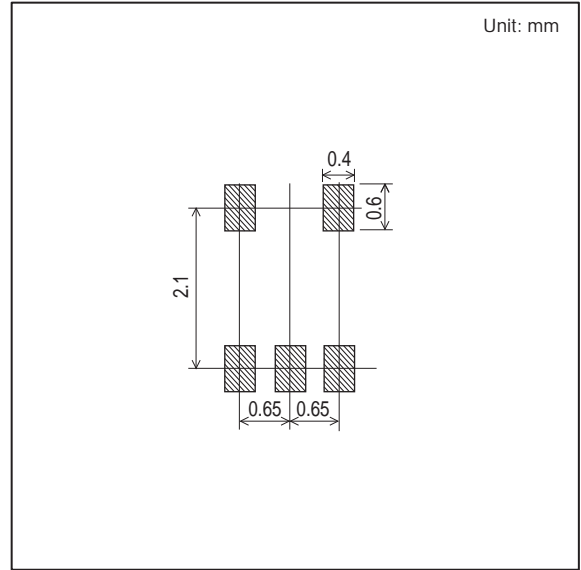
MCH5908

Outline Drawing

MCH5908H-TL-E, MCH5908G-TL-E



Land Pattern Example



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